AD246A Datasheet

Zhuhai Jieli Technology Co.,LTD

Version 1.0

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Revision History

Date	Revision	Description
2025.03.05	V1.0	Initial Release.





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AD246A Features

SYSTEM

- 32bit Dual-Issue DSP 240MHz
- > I-cache
- Support SDTAP/EMU
- On-chip SRAM 52kbyte(share cache ram 20k)
- NOR Flash controller
- Internal RC oscillator,PLL

Audio

- ➤ 1 x 16bit DAC
 - SNR 96dB
 - Noise 11uVrms
 - ❖ Sampling rate 8~96kHz
- 1 x 16bit Class-D Speaker Driver
 - SNR 95dB
 - ❖ Sampling rate 8~96kHz
 - Drive speaker directly 500mW@4Ω
- 1 x 16bit ADC
 - SNR 96dB
 - ❖ Sampling rate 8~48kHz
 - Support Speaker for microphone
- I²S AUDIO Master/Slave interface

Peripherals

- 1 x Full speed USB
- ➤ 1 x SD host controller
- 3 x Multi-function 16bit timer
- 2 x UART interface
- ➤ 1 x I²C Master/Slave interface
- 3 x SPI Master/Slave interface
- → 4 x MCPWM
- ➤ 1 x GPCRC
- > 1 x 10bit GPADC(16 Channels)
- 20 x GPIO Support function remapping

PMU

- ➤ Soft off current: <3uA
- ➤ Music mode: <6mA@HSB 96M
- ➤ LVD range(3bit):1.7V~2.4V, step100mV
- ➤ HPVDD range 1.8V to 5.5V
- ➤ VPWR range 1.8V to 5.5V

> IOVDD range 2.1V to 3.6V

Packages

QFN32(4mm*4mm)

Temperature

Operating temperature

TC = -20° C to $+85^{\circ}$ C (standard range)

TC = -40° C to $+105^{\circ}$ C (extended range)

Storage temperature -65°C to +150°C

Applications

- Sound Toy
- Audio player



1 Block Diagram

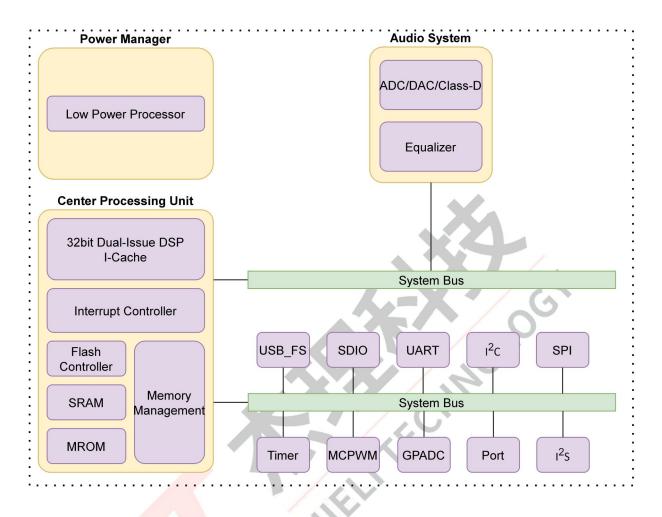


Figure 1-1 AD246A Block Diagram

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2 Pin Definition

2.1 Pin Assignment

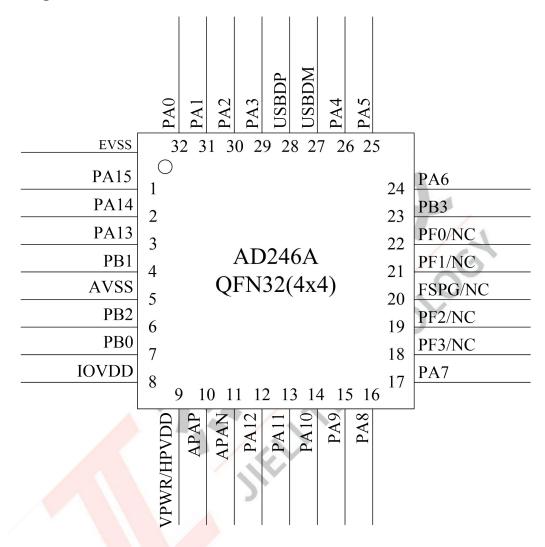


Figure 2-1 AD246A Pin Assignment

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2.2 Pin Description

Table 2-2-1 AD246A Pin Description

Pin	Name		Туре	IO Initial State	Description
No.					AIN_AN(Audio ADC negative Input)
1	PA15		1/0	Z	ADC14(ADC Input Channel 14)
					AIN_A2(Audio ADC Positive Input)
2	PA14		1/0	Z	ADC13(ADC Input Channel 13)
					AIN A0(Audio ADC Positive Input)
3	PA13		I/O	Z	MICBIAS(MIC Bias Output)
	17,125		,, 0	_	ADC12(ADC Input Channel 12)
4	PB1		1/0	Z	AIN_A1(Audio ADC Positive Input)
5	AVSS		G		Audio Ground
6	PB2		1/0	Z	
	1 52		,,,,	_	DAC(AUDIO DAC output)
7	PB0		I/O	Z	ADC15(ADC Input Channel 15)
 	150		,, 0		LVD(External Low Voltage Detection Input)
8	IOVDD		P		IO Power
	VPWR		Р		Chip main power supply
9	HPVDD		P		Audio Power
10	APAP		0	-	Class-D Speaker Driver Positive Output
11	APAN		0		Class-D Speaker Driver Negative Output
					ADC11(ADC Input Channel 11)
12	PA12		1/0	Z	1 ² S LRCK
					ADC10(ADC Input Channel 10)
13	PA11		1/0	Z	1 ² S SCLK
					ADC9(ADC Input Channel 9)
14	PA10		1/0	Z	I ² S DATA1
					I2S_DATA0
15	PA9		I/O(HVT)	10kΩ Pull-down	Firmware Download Interface
			W. 7	10kΩ Pull-up	I ² S MCLK
16	PA8		I/O(HVT)	*Note1	 MCLR(Device Reset)* Note1
				_	NOR Flash D2A
17	PA7		I/O	Z	NOR Flash D3B
	PF3				NOR Flash CSA
18	A0	*Note2	NIO		NOR Flash D0B
	A2/4	NC			
	40	PF2	NIC		NOR FlashD1A
19	A0	*Note2	NIO		NOR Flash CLKB
	A2/4	NC			



Pin No.	Name		Туре	IO Initial State	Description
20	A0	FSPG *Note2	0		NOR Flash Power Gate
	A2/4	NC			
21	A0	PF1 *Note2	NIO		NOR Flash CLKA NOR FlashD1B
	A2/4	NC			
22	A0	PF0 *Note2	NIO		NOR Flash D0A NOR Flash CSB
	A2/4	NC			
23	PB3		1/0	Z	NOR Flash D3A NOR Flash D2B
24	PA6		1/0	Z	ADC8(ADC Input Channel 8)
25	PA5		1/0	Z	ADC7(ADC Input Channel 7) SPIO_DATA3(C)
26	PA4		I/O	Z	ADC6(ADC Input Channel 6) SPIO_DATA2(C)
27	USBDN	1	1/0	15kΩ Pull-down	USB Negative Data ADC5(ADC Input Channel 5)
28	USBDP		I/O	15kΩ Pull-down	USB Positive Data ADC4(ADC Input Channel 4)
29	PA3		1/0	Z	ADC3(ADC Input Channel 3) SPIO_DATA1(C)
30	PA2		1/0	z	ADC2(ADC Input Channel 2) SPIO_DATA0(C)
31	PA1		1/0	Z	ADC1(ADC Input Channel 1) SPIO_CLK(C)
32	PA0		1/0	10kΩ Pull-up *Note1	ADC0(ADC Input Channel 0) Hold down 0 to reset *Note1
PAD	VSS		G		Ground

Note

- $1.10k\Omega$ Pull-up and Hold down 0 to reset function can be disable by efuse in IO Initial State.
- 2.The GPIO is uncontrollable during the initial process.
- 3.IO initial state abbreviations Z--High resistance, H--High level, L--Low level, X--May be changed during power on.
- 4.Timer, MCPWM, UART, I^2C , SPI1/2 and SDIO functions can be remapped to any I/O.

Table 2-2-2 Pin Types Description

Pin Type	Description	Pin Type	Description
Р	Power	1/0	Input or Output
G	Ground	I	Input
NIO	NOR Flash IO	0	Output



3 Electrical Characteristics

3.1 Absolute Maximum Ratings

Table 3-1 Absolute Maximum Ratings

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-20	+85	${\mathbb C}$
Tstg	Storage temperature	-65	+150	$^{\circ}$
VPWR		-0.3	6	V
HPVDD	Supply Voltage	-0.3	6	V
IOVDD		-0.3	3.6	V
GPIO	Input voltage of GPIO (except PA8/PA9)	-0.3	3.6	V
HVTIO	Input voltage of HVT-IO (PA8/PA9)	-0.3	5.5	V

Note

3.2 ESD Ratings

Table 3-2 ESD Ratings

Parameter	Тур	Test pin	Reference standard
Human Body Mode	±4kV	All pins	JEDEC EIA/JESD22-A114
Machine Mode	±200V	All pins	JEDEC EIA/JESD22-A115
Charge Device Model	±2kV	All pins	ANSI/ESDA/JEDEC JS-002-2022

3.3 PMU Characteristics

Table 3-3 PMU Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit		
VPWR	Power supply	-	1.8	5	5.5	V		
Operating mode								
Symbol	Parameter	Conditions	Min	Тур	Max	Unit		
IOVDD	Voltage output			3		V		
טטעטו	Loading current	IOVDD=3.0V@VPWR = 5V			120	mA		
Low Power mo	Low Power mode							
Symbol	Parameter	Conditions	Min	Тур	Max	Unit		
IOVDD	Loading current	IOVDD=3.0V@VPWR = 5V			10	mA		

Note

1. When powered by two dry batteries, the VPWR needs to be merged with IOVDD.

^{1.}Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device.



3.4 IO Characteristics

Table 3-5 IO Characteristics

Input Char	acteristics	Table 3-5 TO Cha				
Symbol	Parameter	Conditions	10	Min	Max	Unit
			PA0~PA15			
			PB0~PB3			
V _{IL}	Low-Level Input Voltage	IOVDD = 3.0V	USBDP	-0.3	1.3	V
			USBDM			
			PA0~PA7			
		IOVDD = 3.0V	PA10~PA15	1.7	3.3	V
			PB0~PB3			
V _{IH}	High-Level Input Voltage		PA8~PA9			
		IOVDD = 3.0V	USBDP	1.7	5.5	V
			USBDM	4/	1	
Output Cha	aracteristics					
Symbol	Parameter	Conditions	10	T	ур	Unit
		10/100 3 01/	PA0~PA7		D=0)	
	Output Current	IOVDD = 3.0V	PA10~PA15	9(HD=1) 15(HD=2) 28(HD=3)		mA
l		Voutput = 0.3V	PB0~PB3			
I _{OL}			PA8~PA9	8		
		IOVDD = 3.0V	USBDP			mA
		Voutput = 0.3V	USBDM			
			PA0~PA7	3(HD=0) 9(HD=1) 15(HD=2) 28(HD=3)		
		IOVDD = 3.0V Voutput = 2.7V	PA10~PA15			mA
l			PB0~PB3			
I _{OH}	Output Current		PA8~PA9	8		
		IOVDD = 3.0V	USBDP			mA
		Voutput = 2.7V	USBDM			
Internal Re	esistance Characteristics					
Symbol	Parameter	Conditions	10	T	ур	Unit
			PA0~PA15	10k(I	PU=1)	
			PB0~PB3	100k(PU=2)	Ω
R_{pu}	Pull-up Resistance	IOVDD = 3.0V	PDU PB3	1M(F	PU=3)	
			USBDP	1.	5k	Ω
			USBDM	18	0k	Ω
			DA ONDA 1 E	10k(I	PD=1)	
		IOVDD = 3.0V	PA0~PA15	100k(PD=2)	Ω
1				1M(PD=3)		
R_{pd}	Pull-down Resistance	IOVDD = 3.0V	PB0~PB3	1M(F	PD=3)	
R_{pd}	Pull-down Resistance	IOVDD = 3.0V	USBDP		PD=3) 5k	Ω

Note

1.Internal pull-up/pull-down resistance accuracy ±20%



3.5 Audio DAC Characteristics

Table 3-5 Mono DAC Characteristics Under VCM 1.3v

Parameter	Conditions	Min	Тур	Max	Unit
Resolution			16		bit
Input Sample Rate		8		96	kHz
	Fin=1kHz@0dBFS				
Output Cuina	Fs=44.1kHz		680		mVrms
Output Swing	B/W=20Hz~20kHz A-Weighted		680		mvrms
Output Resistance	load=100kΩ				
Output Resistance			5		$\mathbf{K} \Omega$
	Fin=1kHz@0dBFS				
CNID	Fs=44.1kHz		93		dB
SIVK	B/W=20Hz~20kHz A-Weighted		93	//	ив
	load=100kΩ		4//		
	Fin=1kHz@-60dBFS				
Dunamia Banga	Fs=44.1kHz		92		dB
Dynamic Range	B/W=20Hz~20kHz A-Weighted		92		иь
	load=100kΩ				
	Fin=1kHz@0dBFS				
THD+N	Fs=44.1kHz	1	-75		dB
I HU+N	B/W=20Hz~20kHz A-Weighted	C.	-/5		ив
	load=100kΩ				
Noise Floor	B/W=20Hz~20kHz A-Weighted		15		uVrms
NOISE FIOUI	load=100kΩ		15		uviiiis



3.6 Class-D Speaker Driver Characteristics

Table 3-6 Class-D Speaker Driver Characteristics Under HPVDD 3.7v

Parameter	Conditions	Min	Тур	Max	Unit
Resolution			16		bit
Output Sample Rate		8		96	kHz
	Differential Mode				
	Fin=1kHz@0dBFS				
SNR	Fs=48kHz		93		dB
	B/W=20Hz~20kHz A-Weighted				
	load=8Ω				
	Differential Mode				
	Fin=1kHz@0dBFS				
Dynamic Range	Fs=48kHz	-	92	·	dB
	B/W=20Hz~20kHz A-Weighted		4//		
	load=8Ω				
	Differential Mode				
	Fin=1kHz@0dBFS				
THD+N	Fs=48kHz	/	-26		dB
	B/W=20Hz~20kHz A-Weighted	1			
	load=8Ω				
		0			
	Differential Mode	V			
Noise Floor	B/W=20Hz~20kHz A-Weighted		45		uVrms
	load=8Ω				
	Differential Mode				
	Fin=1kHz@0dBFS				
Max Output Power	Fs=48kHz		500		mW
	B/W=20Hz~20kHz A-Weighted				
	load=4Ω				



3.7 Audio ADC Characteristics

Table 3-7 Audio ADC Characteristics Under VCM 1.3v

Parameter	Conditions	Min	Тур	Max	Unit
Resolution			16		bit
Output Sample Rate		8		48	kHz
	Differential input Mode				
	Fin=1kHz@1600mVrms				
	Fs=44.1kHz		96		dB
	B/W=20Hz~20kHz A-Weighted				
	ADC gain=0dB				
	Single-ended input Mode				
	Fin=1kHz@800mVrms				
SNR	Fs=44.1kHz		92		dB
	B/W=20Hz~20kHz A-Weighted		4//		
	ADC gain=0dB				
	Single-ended input Mode				
	Fin=1kHz@40mVrms				
	Fs=44.1kHz	<u> </u>	71		dB
	B/W=20Hz~20kHz A-Weighted	7.5			
	ADC gain=27dB		•		
	Differential input Mode	0.			
4	Fin=1kHz@-60dBFS				
	Fs=44.1kHz		96		dB
	B/W=20Hz~20kHz A-Weighted				
	ADC gain=0dB				
	Single-ended input Mode				
	Fin=1kHz@-60dBFS				
Dynamic Range	Fs=44.1kHz		92		dB
	B/W=20Hz~20kHz A-Weighted				
	ADC gain=0dB				
	Single-ended input Mode				
	Fin=1kHz@-60dBFS				
	Fs=44.1kHz		72		dB
	B/W=20Hz~20kHz A-Weighted				
	ADC gain=27dB				
	Differential input Mode				
	Fin=1kHz@1600mVrms				
	Fs=44.1kHz		-80		dB
THD+N	B/W=20Hz~20kHz A-Weighted				
	ADC gain=0dB				
	Single-ended input Mode		70		15
	Fin=1kHz@800mVrms		-78		dB



Parameter	Conditions	Min	Тур	Max	Unit
	Fs=44.1kHz				
	B/W=20Hz~20kHz A-Weighted				
	ADC gain=0dB				
	Single-ended input Mode				
	Fin=1kHz@40mVrms				
	Fs=44.1kHz		-72		dB
	B/W=20Hz~20kHz A-Weighted				
	ADC gain=27dB				
Analogue Gain		-3		27	dB
Max Input Level	Differential input Mode			Vrms	
	ADC gain=0dB	1.6			
	Single-ended input Mode	0.8			.,
	ADC gain=0dB				Vrms



4 Package Information

4.1 QFN32(4mm*4mm)

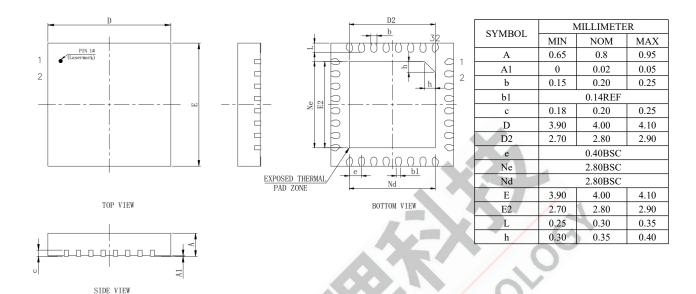


Figure 4-1 AD246A Package



5 IC Marking Information

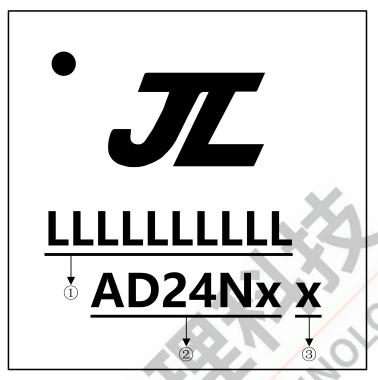


Figure 5-1 AD246A Package Outline

- 1 Production Batch
- 2 AD24Nx Chip Model
- 3 x: Built-in flash size
 - 0: No Flash Memory
 - 2: 2Mbit Flash
 - 4: 4Mbit Flash
 - 8: 8Mbit Flash
 - 6: 16Mbit Flash
 - 3: 32Mbit Flash
 - 5: 64Mbit Flash
 - 7: 128Mbit Flash



6 Solder-Reflow Condition

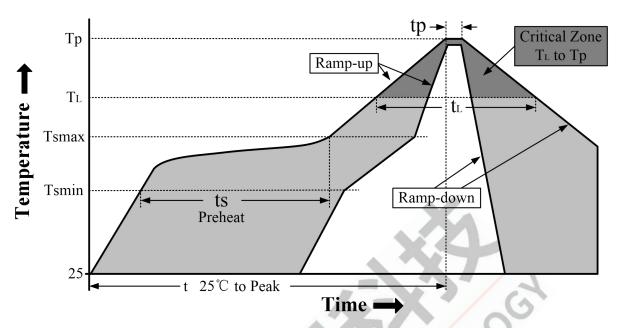


Figure 6-1 Classification Reflow Profile

Table 6-1 Classification Profiles

	Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly	
	Temperature Min (T _{smin})	100℃	150℃	
Preheat/Soak	Temperature Max (T _{smax})	150°C	200℃	
	Time (ts) from (T _{smin} to T _{smax})	60-120 seconds	60-180 seconds	
Average ramp-	up rate (T _{smax} to T _p)	3℃/second max	3℃/second max	
Liquidous temp	perature (T _L)	183℃	217℃	
Time (t _L) maint	ained above T _L	60-150 seconds	60-150 seconds	
Peak package b	ood <mark>y temperature (T_p)</mark>	See Table 6-2	See Table 6-3	
Time within 5℃ of actual		10-30 seconds 20-40 seconds		
Peak Temperature (tp) ²		10-50 seconds	20-40 seconds	
Ramp-down rate (Tp to TL)		6°C/second max	6℃/second max	
Time 25℃ to peak temperature		6 minutes max	8 minutes max	

Note

- 1.All temperatures refer to topside of the package, measured on the package body surface
- 2.Time within 5 $^{\circ}$ C of actual peak temperature (tp) specified for the reflow profiles is a "supplier" and "user" maximum.

Table 6-2 SnPb Classification Temperature

Package	Volume mm ³	Volume mm³
Thickness	< 350	≥ 350
<2.5 mm	240 +0/-5℃	225 +0/-5 ℃
≥2.5 mm	225 +0/-5℃	225 +0/-5°C



Table 6-3 Pb-free	 Classification 	Temperature
-------------------	------------------------------------	-------------

Package	Volume mm ³	Volume mm³	Volume mm ³
Thickness	< 350	350 - 2000	> 2000
< 1.6mm	260℃	260℃	260℃
1.6 mm - 2.5mm	260℃	250℃	245 ℃
> 2.5mm	250℃	245℃	245 ℃

Note

1.*Tolerance The device manufacturer/supplier shall assure process compatibility up to and including the stated classification temperature (this means Peak reflow temperature +0 $^{\circ}$ C.For example 260 $^{\circ}$ C+0 $^{\circ}$ C)at the rated MSL level.

7 Storage Condition

7.1 Moisture Sensitivity Level

AD24N is qualified to moisture sensitivity level MSL3 in accordance with JEDEC J-STD-033

7.2 Storage Alert

- 1. Calculated shelf life in sealed bag 12 months at \leq 40°C and 90 $\frac{1}{8}$ relative humidity (RH).
- 2. Peak package body temperature≤260°C.
- 3. After bag is opened, devices that will be subjected to reflow solder or other high temperature process must be mounted within 168 hours of factory conditions≤30°C/60%RH or stored per J-STD-033.
- 4. Devices require bake before mounting if humidity indicator card reads > 10% for level 2a-5a devices or > 60% for level 2 devices when read at 23±5°C, or 3a or 3b are not met.
- 5. Please refer to IPC/JEDEC J-STD-033 for baking procedure if necessary.